

Single-layer Group-IVB nitride halides as promising photocatalysts

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Table S1 The calculated lattice constants of bulk β -form MNX with PBE functional with or without vdW correction compared with experimental results.

	PBE		PBE+ vdW-optB88		Experiment	
	a	c	a	c	a	c
ZrNCl	3.647	28.694	3.642	27.730	3.605	27.672 ¹
ZrNBr	3.682	30.341	3.676	29.465	3.640	29.270 ²
ZrNI	3.758	32.509	3.756	31.729	3.718	31.381 ²
HfNCl	3.589	28.517	3.580	27.643	3.577	27.711 ¹
HfNBr	3.628	31.377	3.618	29.430	3.610	29.294 ²
HfNI	3.710	36.136	3.703	31.666	3.689	31.329 ²

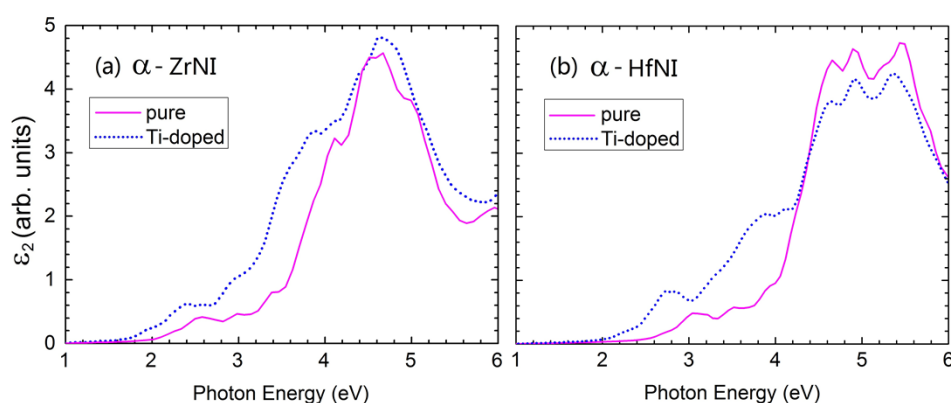


Fig.S1 Imaginary part of the dielectric function, ϵ_2 , as a function of photon energy $\hbar\omega$ for (a) pure and 12.5% Ti-doped single-layer α -ZrNI and (b) pure and 12.5% Ti-doped single-layer α -HfNI. ϵ_2 is calculated using the PBE functional followed by a rigid energy shift to take into account the bandgap underestimation of the PBE functional.

1. X. Chen, T. Koiwasaki and S. Yamanaka, *Journal of Solid State Chemistry*, 2001, **159**, 80-86.
2. X. Chen, H. Fukuoka and S. Yamanaka, *Journal of Solid State Chemistry*, 2002, **163**, 77-83.